This GIDEP PCN is to announce changes in datasheet parameters for the following International Rectifier Part No

**IRHLF77110 (2N7608T2)**
100V 100kRad Hi-Rel Single N-Channel TID Hardened MOSFET in a TO-205AF package

**Source-Drain Diode Ratings and Characteristics**

VSD Diode Forward Voltage @ Tj = 25°C, IS = 6.0A, VGS = 0V
Change max limit from 1.2V to 1.4V

Table 1. Electrical Characteristics @ Tj = 25°C, Post Total Dose Irradiation (Per Die)

VSD Diode Forward Voltage @ VGS = 0V, ID = 6.0A
Change max limit from 1.2V to 1.4V

Reference: IR Datasheet PD-97062